

**5HN01N**

## Ultrahigh-Speed Switching Applications

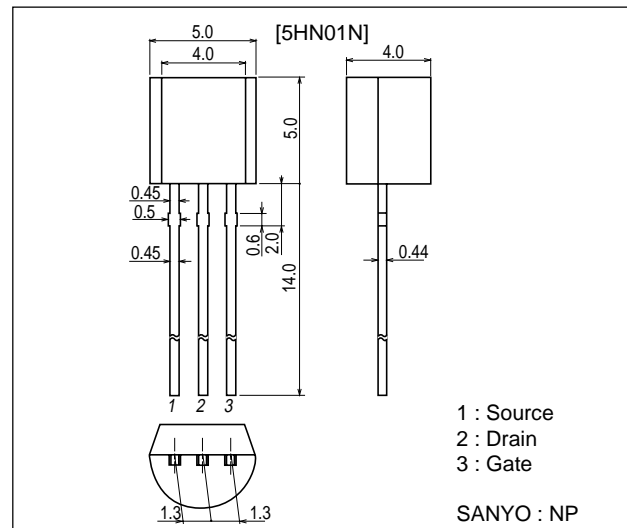
### Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

### Package Dimensions

unit : mm

2178



### Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		50	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±20	V
Drain Current (DC)	I <sub>D</sub>		0.1	A
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycle≤1%	0.4	A
Allowable Power Dissipation	P <sub>D</sub>		0.4	W
Channel Temperature	T <sub>ch</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	50			V
Zero-Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =50V, V <sub>GS</sub> =0			10	μA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =100μA	1		2.4	V

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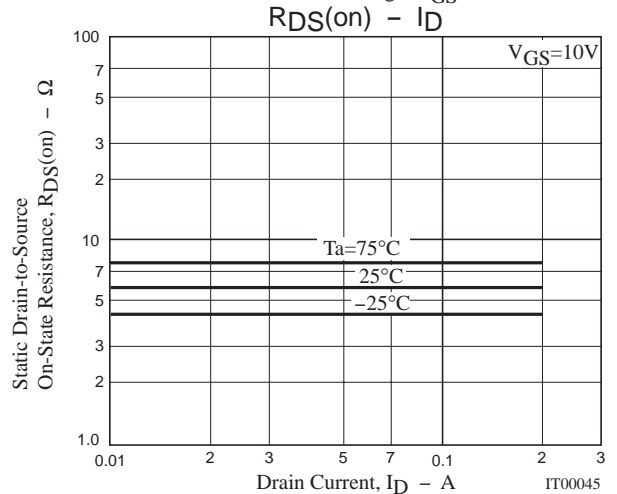
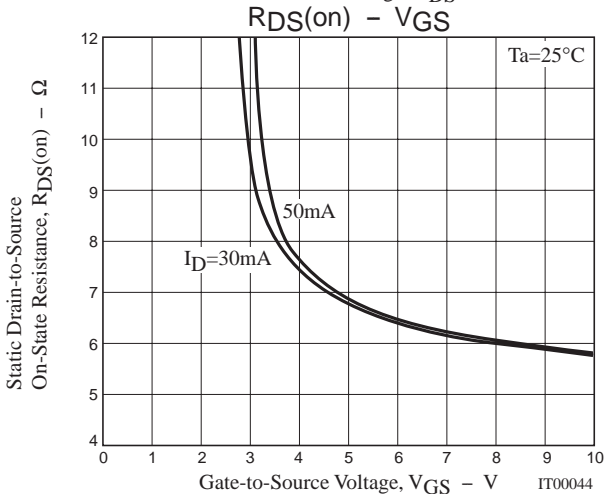
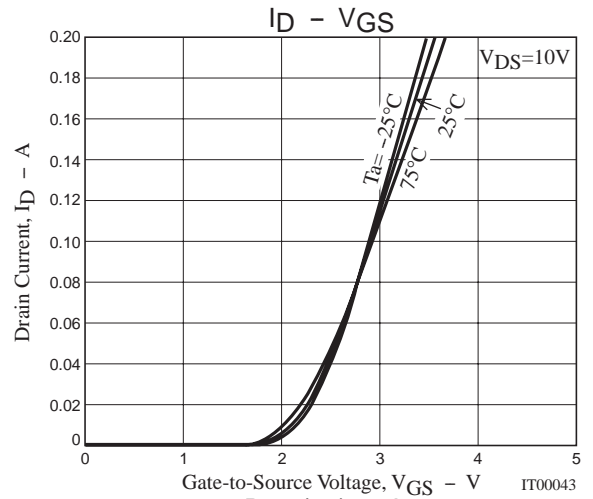
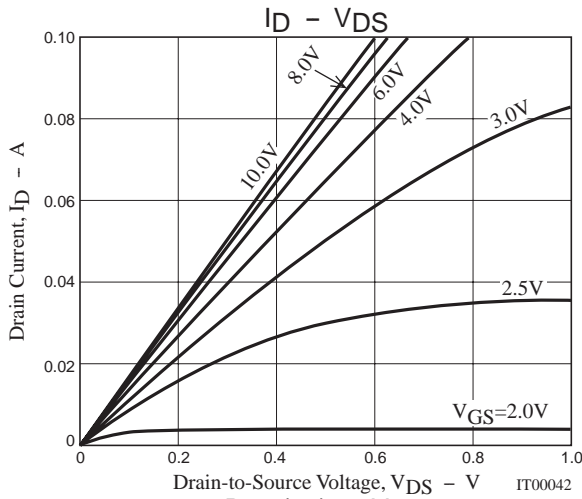
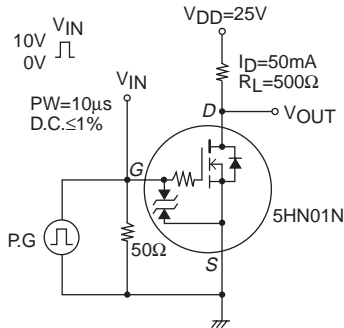
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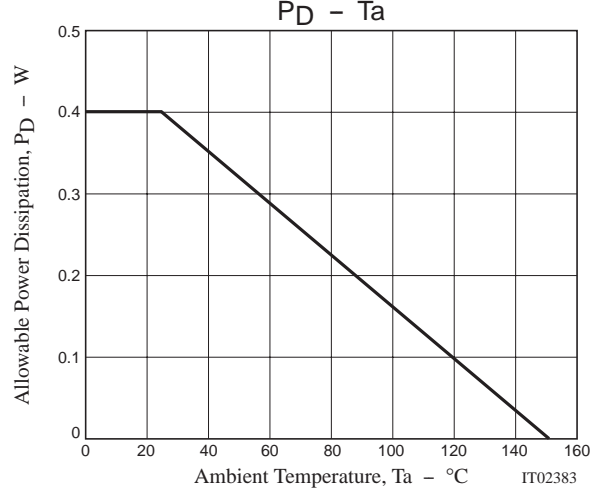
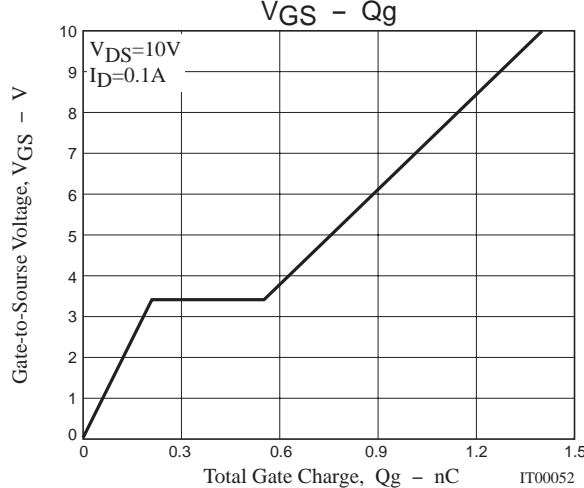
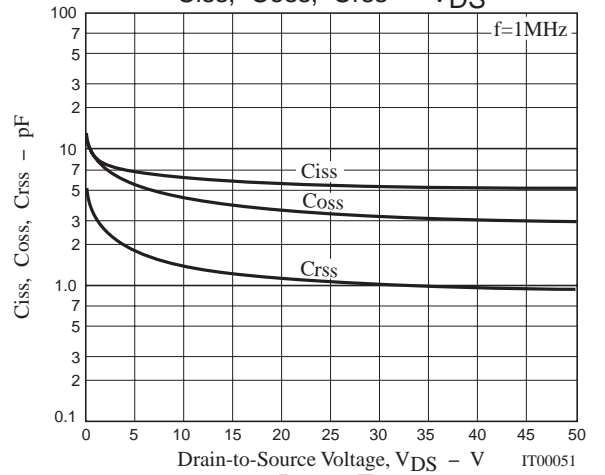
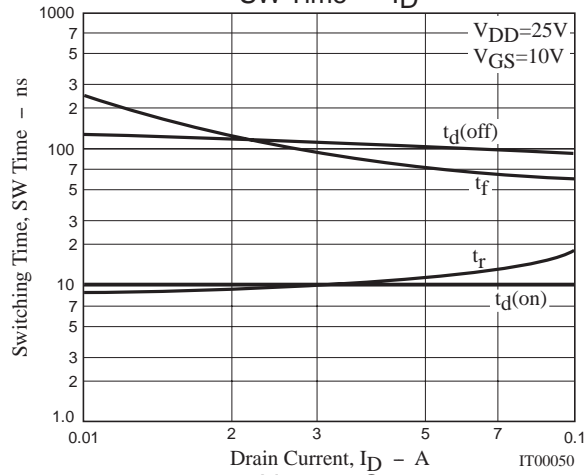
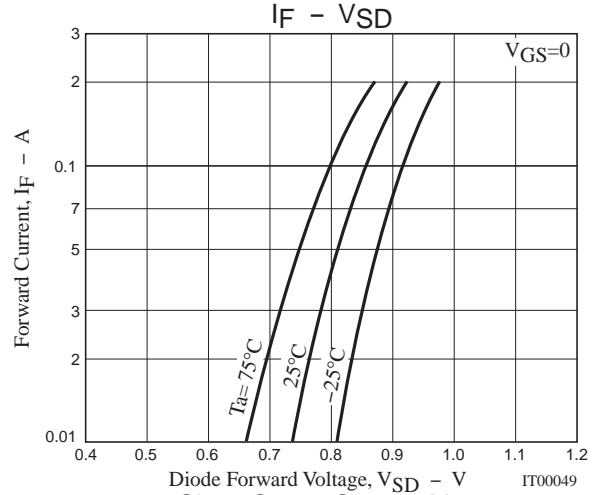
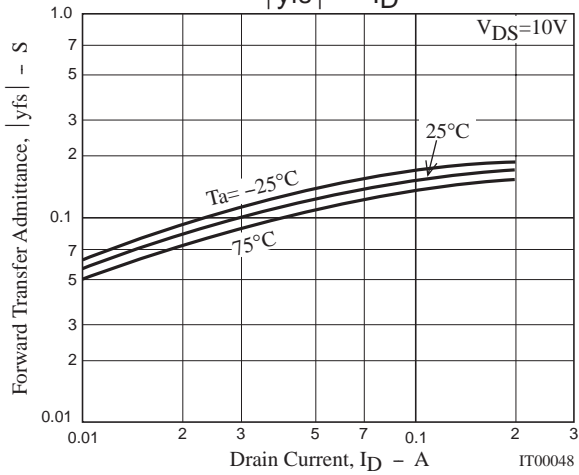
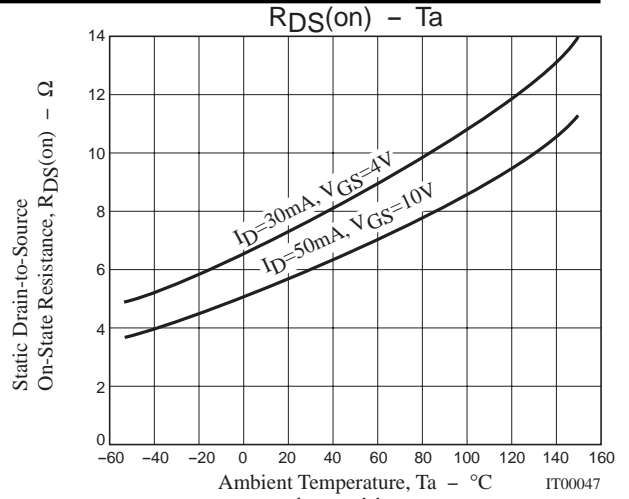
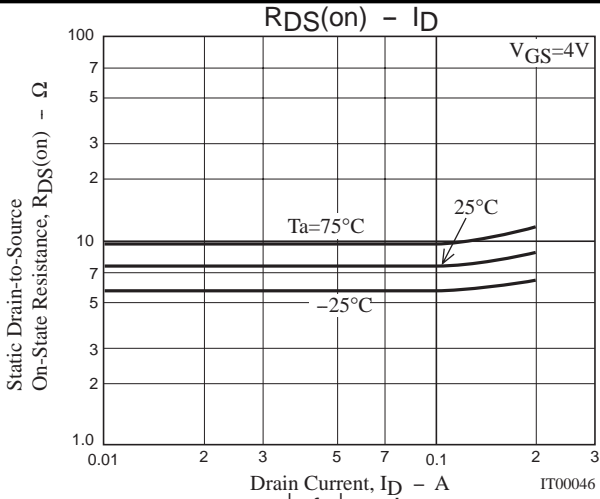
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=50mA$	85	120		mS
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=50mA, V_{GS}=10V$		5.8	7.5	$\Omega$
	$R_{DS(on)2}$	$I_D=30mA, V_{GS}=4V$		7.5	10.5	$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=10V, f=1MHz$		6.2		pF
Output Capacitance	$C_{oss}$	$V_{DS}=10V, f=1MHz$		4.4		pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS}=10V, f=1MHz$		1.5		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit		10		ns
Rise Time	$t_r$	See specified Test Circuit		11		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit		105		ns
Fall Time	$t_f$	See specified Test Circuit		75		ns
Total Gate Charge	$Q_g$	$V_{DS}=10V, V_{GS}=10V, I_D=100mA$		1.40		nC
Gate Source Charge	$Q_{gs}$	$V_{DS}=10V, V_{GS}=10V, I_D=100mA$		0.21		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$	$V_{DS}=10V, V_{GS}=10V, I_D=100mA$		0.34		nC
Diode Forward Voltage	$V_{SD}$	$I_S=100mA, V_{GS}=0$		0.85	1.2	V

Marking : YC

## Switching Time Test Circuit



# 5HN01N



Note on usage : Since the 5HN01N is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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